

## Features

- Interdigitated amplifying gates
- Fast turn-on and high  $dI/dt$
- Low switching losses

## Typical Applications

- Inductive heating
- Electronic welders
- Self-commutated inverters

$I_{T(AV)}$	<b>490A</b>
$V_{DRM}/V_{RRM}$	<b>800~1600V</b>
$t_q$	<b>18~50μs</b>
$I_{TSM}$	<b>4.3 kA</b>
$I^2t$	<b>92 10<sup>3</sup> A<sup>2</sup>S</b>



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j$ (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Double side cooled,	$T_c=55^\circ C$ $T_c=85^\circ C$	125		490	A
						330	
$V_{DRM}$ $V_{RRM}$	Repetitive peak off-state voltage Repetitive peak reverse voltage	$V_{DRM} \& V_{RRM}$ , $t_p=10ms$ $V_{DSM} \& V_{RSM}=V_{DRM} \& V_{RRM}+100V$	125	800		1600	V
$I_{DRM}$ $I_{RRM}$	Repetitive peak current	$V_D=V_{DRM}$ $V_R=V_{RRM}$	125			30	mA
$I_{TSM}$	Surge on-state current	10ms half sine wave	125			4.3	kA
$I^2t$	$I^2t$ for fusing coordination	$V_R=0.6V_{RRM}$				92	A <sup>2</sup> s*10 <sup>3</sup>
$V_{TO}$	Threshold voltage		125			1.60	V
$r_T$	On-state slop resistance					1.32	mΩ
$V_{TM}$	Peak on-state voltage	$I_{TM}=1000A$ , $F=7.0kN$	125			2.92	V
$dv/dt$	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			500	V/μs
$di/dt$	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$ to 800A, Gate pulse $t_r \leq 0.5\mu s$ $I_{GM}=1.5A$ $f=1Hz$	125			1200	A/μs
$Q_{fr}$	Recovery charge	$I_{TM}=1000A$ , $tp=2000\mu s$ , $di/dt=-60A/\mu s$ , $V_R=50V$	125		350		μC
$t_q$	Circuit commutated turn-off time	$I_{TM}=500A$ , $tp=1000\mu s$ , $V_R=50V$ $dv/dt=30V/\mu s$ , $di/dt=-20A/\mu s$	125	18		50	μs
$I_{GT}$	Gate trigger current	$V_A=12V$ , $I_A=1A$	25	40		250	mA
$V_{GT}$	Gate trigger voltage			0.9		2.5	V
$I_H$	Holding current			20		400	mA
$V_{GD}$	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.3			V
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 7.0kN				0.045	°C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.010	
$F_m$	Mounting force			5.3		10	kN
$T_{stg}$	Stored temperature			-40		140	°C
$W_t$	Weight				80		g
Outline		KT25aT					

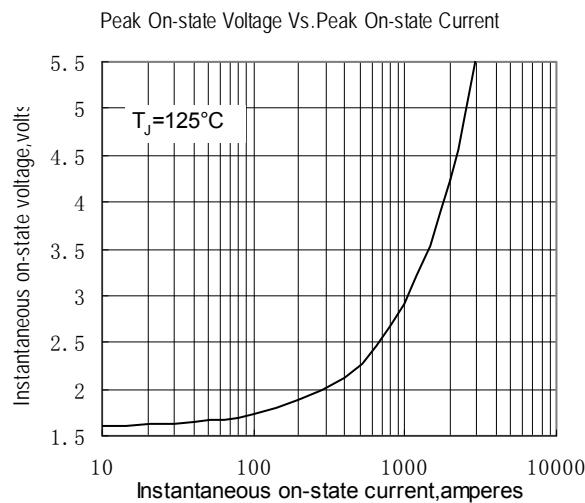


Fig.1

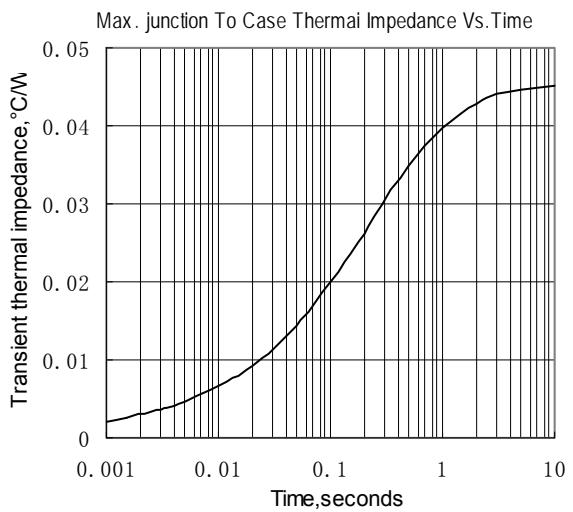


Fig.2

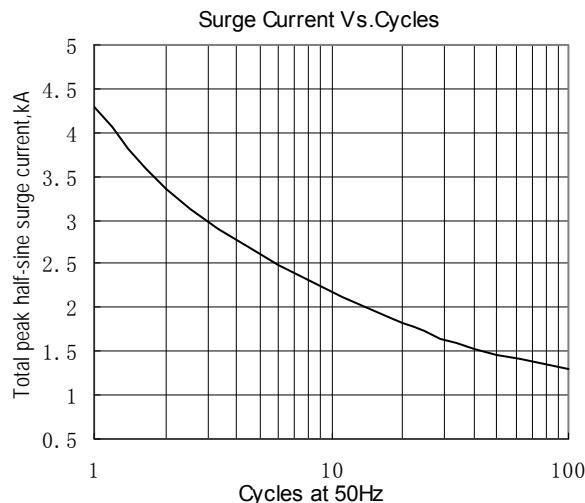


Fig.3

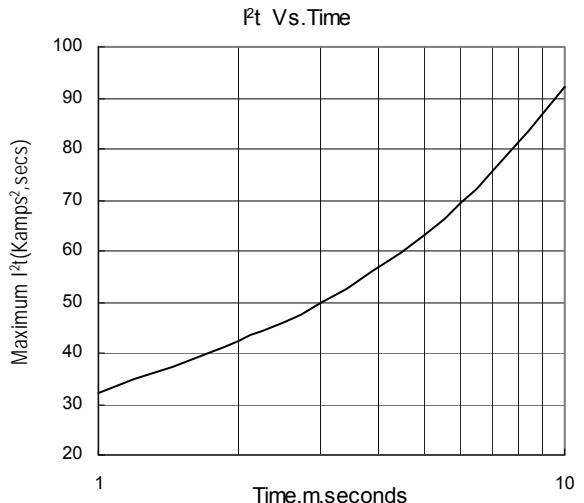


Fig.4

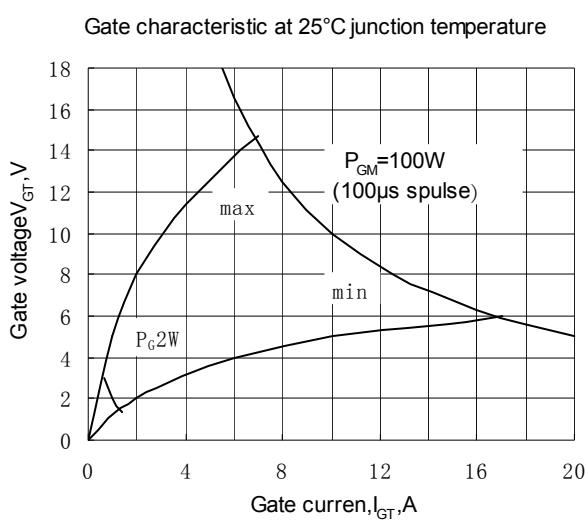


Fig.5

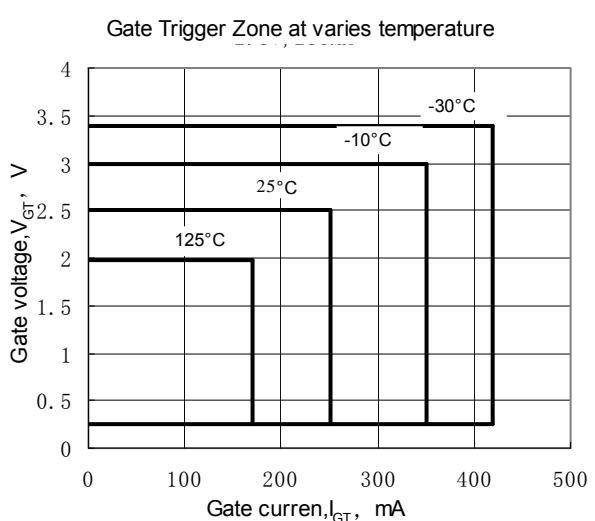


Fig.6

**Outline:**